

Ordering number : ENN7362

PNP Epitaxial Planar Silicon Transistor

**30A02SS**

Low-Frequency General-Purpose Amplifier Applications

Applications

- Low-frequency Amplifier, high-speed switching, small motor drive.

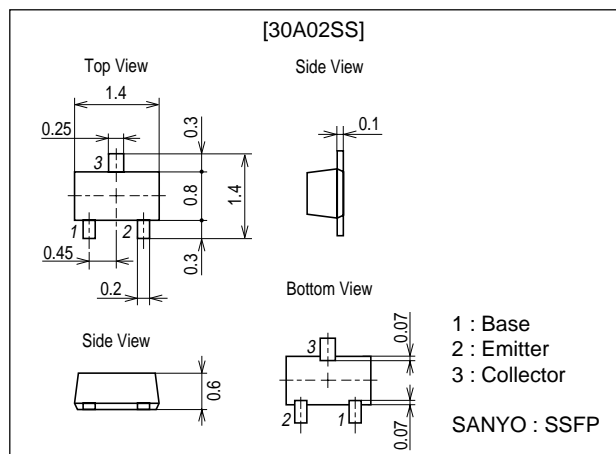
Features

- Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance).
R_{CE(sat)} typ=580mΩ [I_C=0.7A, I_B=35mA].
- Ultrasmall package facilitates miniaturization in end products.
- Small ON-resistance (Ron).

Package Dimensions

unit : mm

2159A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		-30	V
Collector-to-Emitter Voltage	V _{CEO}		-30	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	I _C		-600	mA
Collector Current (Pulse)	I _{CP}		-1.2	A
Collector Dissipation	P _C	Mounted on a glass epoxy board (20X30X1.6mm)	200	mW
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =-30V, I _E =0			-100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =-4V, I _C =0			-100	nA
DC Current Gain	h _{FE}	V _{CE} =-2V, I _C =-10mA	200		500	
Gain-Bandwidth Product	f _T	V _{CE} =-10V, I _C =-50mA		520		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		4.7		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =-200mA, I _B =-10mA		-110	-220	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-200mA, I _B =-10mA		-0.9	-1.2	V

Marking : XM

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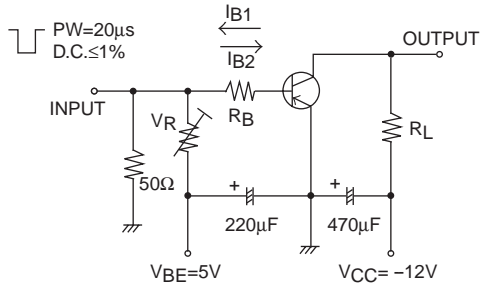
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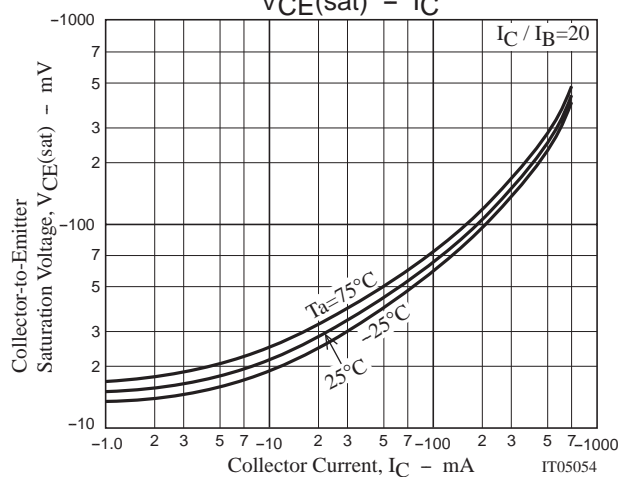
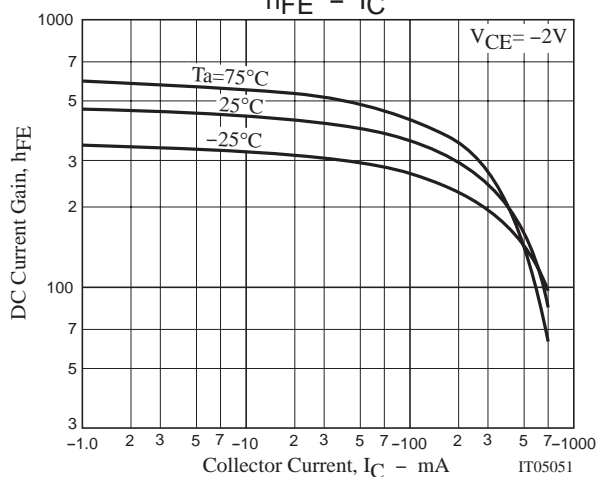
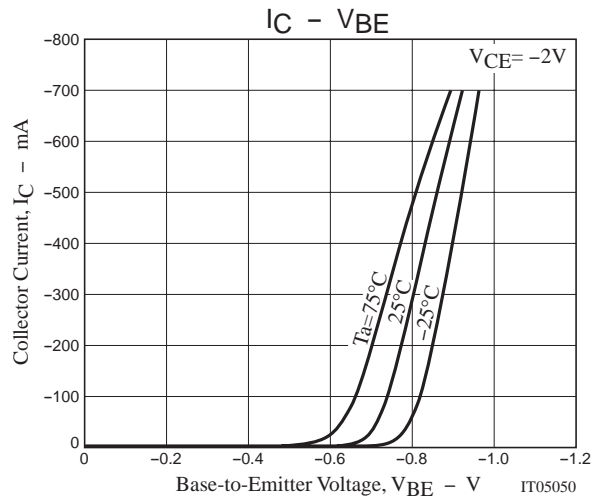
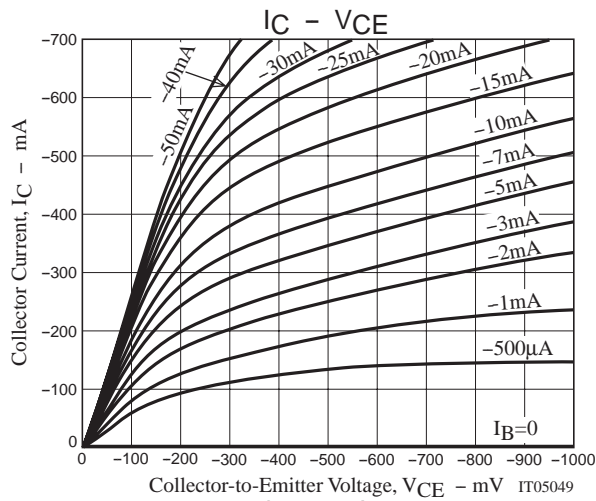
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0$	-30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0$	-5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}	See specified Test Circuit.		125		ns
Fall Time	t_f	See specified Test Circuit.		25		ns

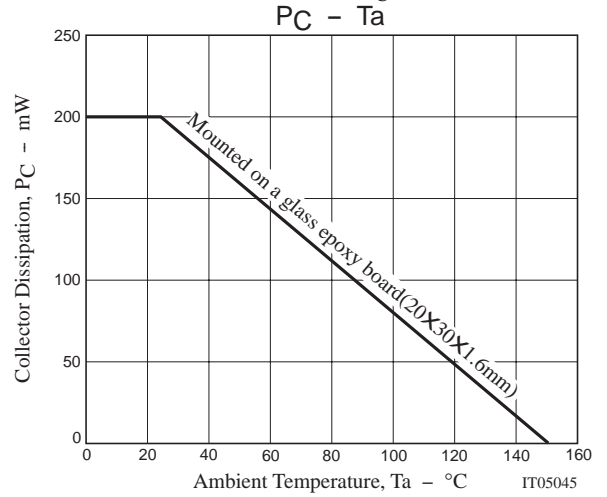
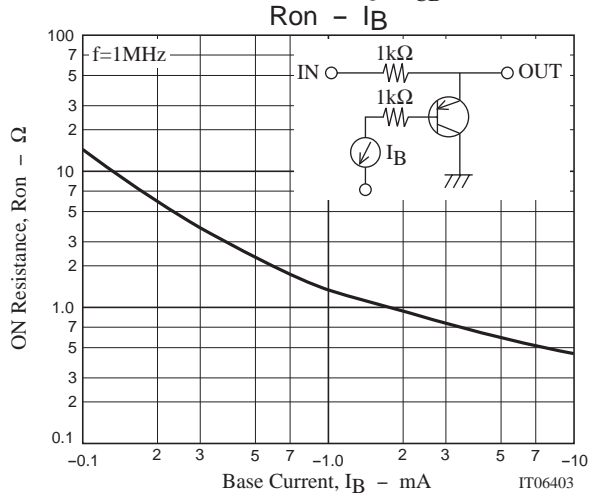
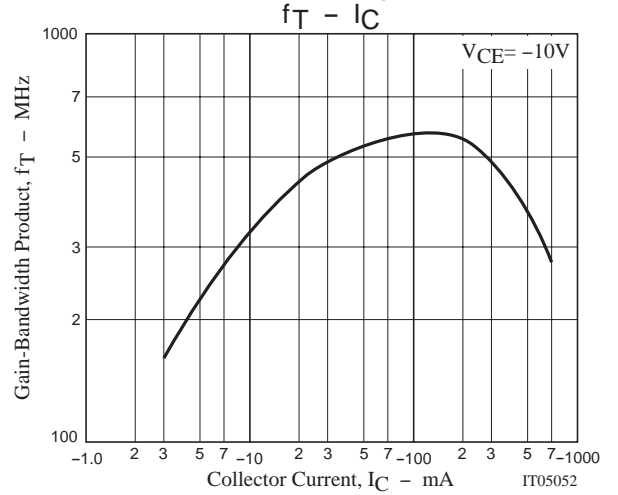
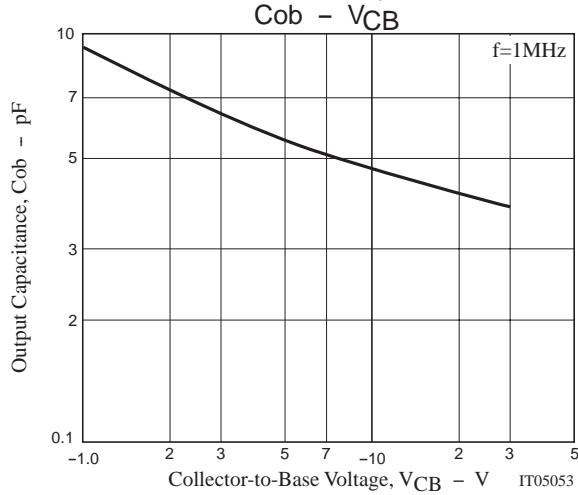
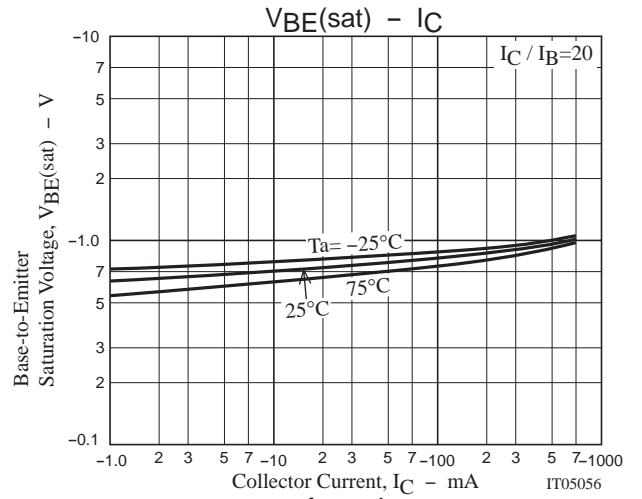
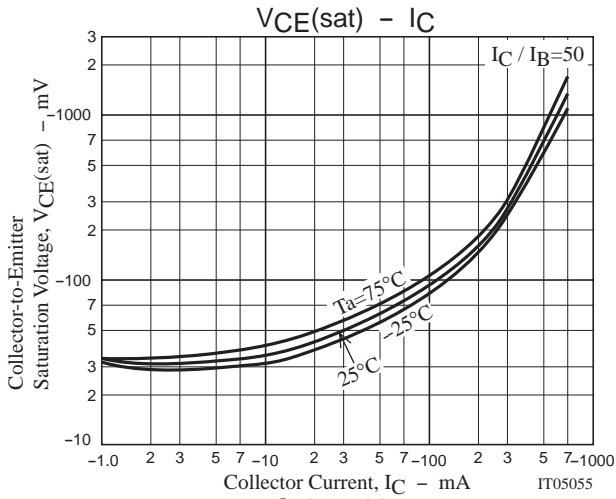
Switching Time Test Circuit



$$I_C = 20I_{B1} = -20I_{B2} = -300mA$$



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